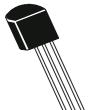


# Continental Device India Limited

An IS/ISO 9002 and IECQ Certified Manufacturer



## **SILICON PLANAR EPITAXIAL TRANSISTORS**



BC 413, B, C BC 414, B, C

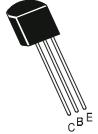
**TO-92 Plastic Package** 

# **Low Noise Transistors**

DESCRIPTION	SYMBOL	BC 413	BC414	UNITS
Collector Emitter Voltage	$V_{CEO}$	30	45	V
Collector Base Voltage	$V_{CBO}$	45	50	V
Emitter Base Voltage	$V_{EBO}$	5.	5.0	
Collector Current Continuous	I <sub>C</sub>	10	00	mA
Total Device Dissipation@ Ta=25ºC	$P_{D}$	350		mW
Derate Above 25°C		2.	8	mW/ °C
Total Device Dissipation@ Tc=25°C	$P_D$	1.	0	W
Derate Above 25°C		8.	0	mW/ °C
Operating And Storage Junction Temperature Range	$T_{j},T_{stg}$	-55 to +150		°C
THERMAL RESISTANCE				
Junction to ambient	$R_{th(j-a)}$	35	57	°C/W
Junction to case	$R_{th(j-c)}$	12	25	°C/W

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ELECTRICAL CHARACTERISTICS (Ta=25°C unless specified otherwise)

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DESCRIPTION	SYMBO	TEST CONDITION	MIN	TYP	MAX	UNITS		
Collector Emitter Breakdown Voltage	$BV_{CEO}$	$I_C=10mA, I_B=0$						
BC413			30			V		
BC414			45			V		
Collector Base Breakdown Voltage	$BV_{CBO}$	$I_C=10uA$ , $I_E=0$						
BC413			45			V		
BC414			50			V		
Emitter Base Breakdown Voltage	$BV_{EBO}$	$I_E=10uA, I_C=0$	5			V		
Collector-Cut off Current	$I_{CBO}$	$V_{CB} = 30V$ , $I_E = 0$			15	nA		
		$V_{CB} = 30V, I_{E} = 0$			5	μΑ		
		Ta = +125 <sup>O</sup> C						
Emitter cut off Current	I <sub>EBO</sub>	$V_{EB} = 4V, I_{C} = 0$			15	nA		
	200	25 / 0						
DC Current Gain	$h_FE$							
BC413B, BC414B		$I_C=10uA, V_{CE}=5V$	100					
BC413C, BC414C			100					
BC413B, BC414B		$I_C=2mA, V_{CE}=5V$	180		460			
BC413C, BC414C			380		800			
BC413, BC414			180		800			
Collector Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C=10\text{mA}, I_B=0.5\text{mA}$			0.25	V		
		I <sub>C</sub> =10mA,I <sub>B</sub> =see note	e 1		0.60	V		
	V <sub>CE(sat) 2</sub>	$I_C=100$ mA, $I_B=5$ mA			0.60	V		
	. ,							
Base Emitter Saturation Voltage		$I_C=100$ mA, $I_B=5$ mA		1.10		V		
Base Emitter On Voltage	$V_{BE(on)}$	$I_C=10uA, V_{CE}=5V$		0.52		V		
		$I_C=100uA, V_{CE}=5V$		0.55		V		
		$I_C=2mA, V_{CE}=5V$	0.55		0.75	V		

**ELECTRICAL CHARACTERISTICS (Ta=25°C unless specified otherwise)** 

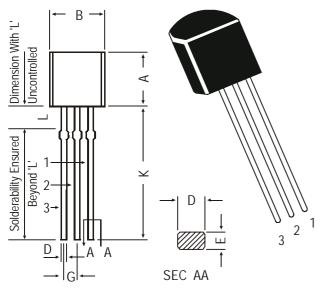
DESCRIPTION	SYMBO	LTEST CONDITION	MIN	TYP	MAX	UNITS	
DYNAMIC CHARACTERISTICS							
Transition Frequency	$f_T$	$I_C=10mA$ , $V_{CE}=5V$		250		MHz	
		f=100MHz					
Collector Base Capacitance	$C_cbo$	$V_{CF} = 10V, I_F = 0,$		2.5		pF	
	CDO	f =1MHz				'	
Noise Figure	NF	I <sub>C</sub> =0.2mA, V <sub>CE</sub> =5V			2.5	dB	
<b>G</b>		$R_S=2K\Omega$ f=30Hz-15k	ΚHz				

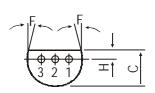
Note 1 : I<sub>B</sub> is value for which I<sub>C</sub> =11mA@ V<sub>CE</sub> =1V

Note 2 : Pulse test =  $300\mu$ s, Duty Cycle 2%.

## **TO-92 Plastic Package**

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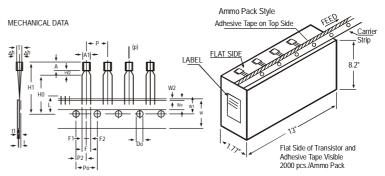
## PIN CONFIGURATION

- 1. EMITTER
- BASE 2.
- 3. COLLECTOR

DIM	MIN.	MAX.				
Α	4.32	5.33				
В	4.45	5.20				
С	3.18	4.19				
D	0.41	0.55				
Ε	0.35	0.50				
F	5 DEG					
G	1.14	1.40				
Н	1.14	1.53				
K	12.70	_				
L	1.982	2.082				

All diminsions in mm.

#### **TO-92 Transistors on Tape and Ammo Pack**



#### All dimensions in mm unless specified otherwise

ITEM		SPECIFICATION					
ITEM	SYMBOL	MIN.	IIN. NOM. MAX. TOL.		TOL.	REMARKS	
BODY WIDTH	A1	4.0		4.8			
BODY HEIGHT	Α	4.8		5.2			
BODY THICKNESS	Ţ	3.9		4.2	١.		
PITCH OF COMPONENT	Р		12.7	l	±1		
FEED HOLE PITCH	Po		12.7		±0.3	CUMULATIVE PITCH ERROR 1.0 mm/20 PITCH	
FEED HOLE CENTRE TO	D0		/ 25	l			
COMPONENT CENTRE	P2		6.35		±0.4	TO BE MEASURED AT BOTTOM OF CLINCH	
DISTANCE BETWEEN OUTER	_			l	+0.6		
LEADS	F		5.08	_	-0.2	4T TOD OF DOD'/	
COMPONENT ALIGNMENT	∆h		0 18	1		AT TOP OF BODY	
TAPE WIDTH HOLD-DOWN TAPE WIDTH	W Wo		6	l	±0.5 ±0.2		
HOLE POSITION	W1		9	l	+0.7		
HOLE POSITION	VVI		7		-0.5		
HOLD-DOWN TAPE POSITION	W2		0.5	l	±0.2		
LEAD WIRE CLINCH HEIGHT	Но		16	l	±0.5		
COMPONENT HEIGHT	H1			23.25			
LENGTH OF SNIPPED LEADS	L		١.	11.0	١		
FEED HOLE DIAMETER	Do		4	1,,	±0.2		
TOTAL TAPE THICKNESS	t F2		2.54	1.2		t1 0.3 - 0.6	
LEAD - TO - LEAD DISTANCEF1,	F2		2.54	l	+0.4		
CLINCH HEIGHT	H2			3	0.1		
PULL - OUT FORCE	(P)	6N					

#### NOTES

- NOTES

  1. MAXIMUM ALIGNMENT DEVIATION BETWEEN LEADS NOT TO BE GREATER THAN 0.2 mm.

  2. MAXIMUM NON-CUMULATIVE VARIATION BETWEEN TAPE FEED HOLES SHALL NOT EXCEED 1 mm IN 20 PITCHES.

  3. HOLDDOWN TAPE NOT TO EXCEED BEYOND THE EDGE(S) OF CARRIER TAPE AND THERE SHALL BE NO
- 3. HOLDDOWN TAPE NOT TO EXCEED BEYOND THE EDGE(S) OF CARRIER TAPE AND THERE SHALL BE NO EXPOSURE OF ADHESIVE.
   4. NO MORE THAN 3 CONSECUTIVE MISSING COMPONENTS ARE PERMITTED.
   5. A TAPE TRAILER, HAVING AT LEAST THREE FEED HOLES ARE REQUIRED AFTER THE LAST COMPONENT.
   6. SPLICES SHALL NOT INTERFERE WITH THE SPROCKET FEED HOLES.

# Packing Detail

1 doking botan									
PACKAGE	STANDARD PACK		INNER CARTON BOX		OUTER CARTON BOX				
	Details	Net Weight/Qty	Size	Qty	Size	Qty	Gr Wt		
TO-92 Bulk	1K/polybag	200 gm/1K pcs	3" x 7.5" x 7.5"	5K	17" x 15" x 13.5"	80K	23 kgs		
TO-92 T&A	2K/ammo box	645 gm/2K pcs	12.5" x 8" x 1.8"	2K	17" x 15" x 13.5"	32K	12.5 kgs		

**Notes** 

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TO-92 Plastic Package

#### **Disclaimer**

The product information and the selection guides facilitate selection of the CDIL's Discrete Semiconductor Device(s) best suited for application in your product(s) as per your requirement. It is recommended that you completely review our Data Sheet(s) so as to confirm that the Device(s) meet functionality parameters for your application. The information furnished in the Data Sheet and on the CDIL Web Site/CD is believed to be accurate and reliable. CDIL however, does not assume responsibility for inaccuracies or incomplete information. Furthermore, CDIL does not assume liability whatsoever, arising out of the application or use of any CDIL product; neither does it convey any license under its patent rights nor rights of others. These products are not designed for use in life saving/support appliances or systems. CDIL customers selling these products (either as individual Discrete Semiconductor Devices or incorporated in their end products), in any life saving/support appliances or systems or applications do so at their own risk and CDIL will not be responsible for any damages resulting from such sale(s).

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